

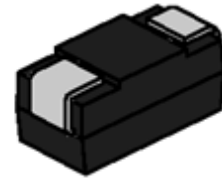


CP0080ABN TSS

Rev.3.1

DESCRIPTION:

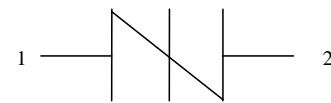
The thyristors of CP0080ABN are a type of semiconductor component. They are designed to protect baseband equipment such as phones, modems, line cards, answering machines, FAX machines, CPE and DSL from damaging overvoltage transients.



SMA

FEATURES:

- ✧ Excellent capability of absorbing transient surge.
- ✧ Quick response to surge voltage (ns Level).
- ✧ Eliminates overvoltage caused by fast rising transients.
- ✧ Moisture sensitivity level: Level 1.
- ✧ UL 497B item recognized. (File No.: E480698).
- ✧ IEC61000-4-2 (ESD) $\pm 30\text{kV}$ (air), $\pm 30\text{kV}$ (contact).
- ✧ Low capacitance.
- ✧ Non degenerative.



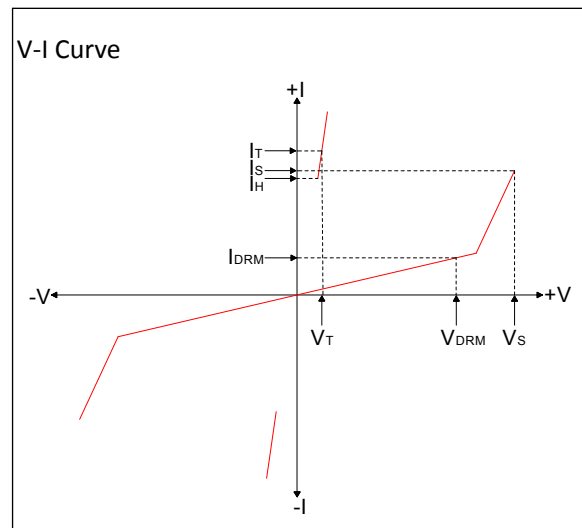
Symbol

ABSOLUTE MAXIMUM RATINGS ($T_A=25^\circ\text{C}$, RH=45%-75%, unless otherwise noted)

Parameter	Symbol	Value	Unit
Storage temperature range	T_{STG}	-60 to +150	$^\circ\text{C}$
Operating junction temperature range	T_J	-40 to +125	$^\circ\text{C}$
Repetitive peak pulse current@10/1000 μs	I_{PP}	80	A

ELECTRICAL CHARACTERISTICS ($T_A=25^\circ\text{C}$)

Symbol	Parameter
V_{DRM}	Peak off-state voltage
I_{DRM}	Off-state current
V_S	Switching voltage
I_S	Switching current
V_T	On-state voltage
I_T	On-state current
I_H	Holding current
C_O	Off-state capacitance



MARKING



P8ABN: Device Marking Code
1828: the 28th week, 2018

ELECTRICAL CHARACTERISTICS (T_A=25°C, continued)

Part Number	I _{DRM} @V _{DRM}		V _S ^① @I _S		V _T @I _T		I _H	C _o ^②		Marking
	μA	V	V	mA	V	A	mA	pF		
	max		max	max	max	max	min	typ	max	
CP0080ABN	1	6	15	800	4	2.2	50	20	24	P8ABN

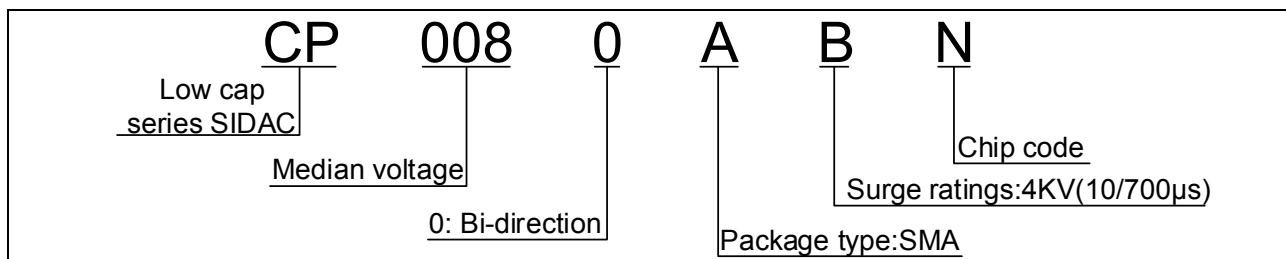
① V_S is measured at 100kV/s

② Off-state capacitance is measured in V_{DC}=2V, V_{RMS}=1V, f=1MHz

SURGE RATINGS

Series	I _{PP} (A) min			
	2/10μs	8/20μs	10/360μs	10/1000μs
B	250	250	125	80

ORDERING INFORMATION



SOLDERING PARAMETERS

Reflow Condition		Pb-Free assembly (see FIG.2)
Pre Heat	-Temperature Min ($T_{S(min)}$)	+150°C
	-Temperature Max($T_{S(max)}$)	+200°C
	-Time (Min to Max) (t_s)	60-180 secs.
Average ramp up rate (Liquidus Temp (T_L) to peak)		3°C/sec. Max
$T_{S(max)}$ to T_L - Ramp-up Rate		3°C/sec. Max
Reflow	-Temperature(T_L) (Liquidus)	+217°C
	-Temperature(t_L)	60-150 secs.
Peak Temp (T_p)		+260(+0/-5)°C
Time within 5°C of actual Peak Temp (t_p)		30 secs. Max
Ramp-down Rate		6°C/sec. Max
Time 25°C to Peak Temp (T_P)		8 min. Max
Do not exceed		+260°C

FIG.1: $t_r \times t_d$ pulse waveform

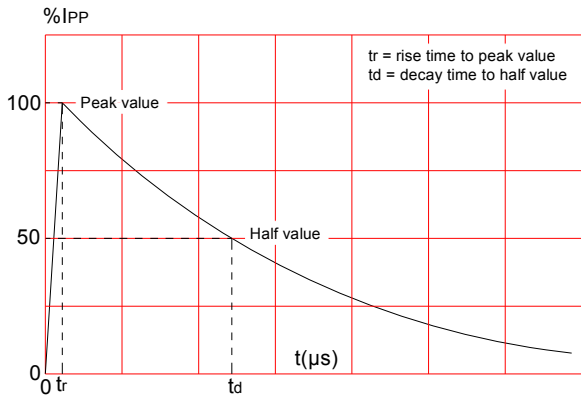


FIG.2: Reflow condition

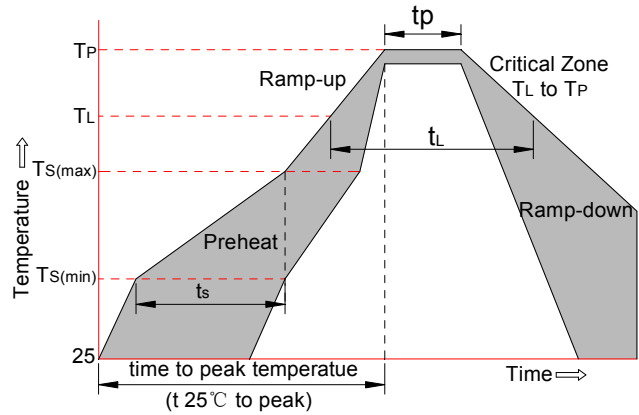


FIG.3: Normalized Vs change vs. junction temperature

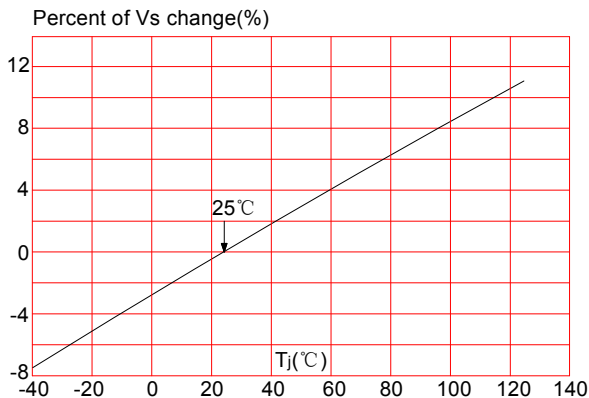
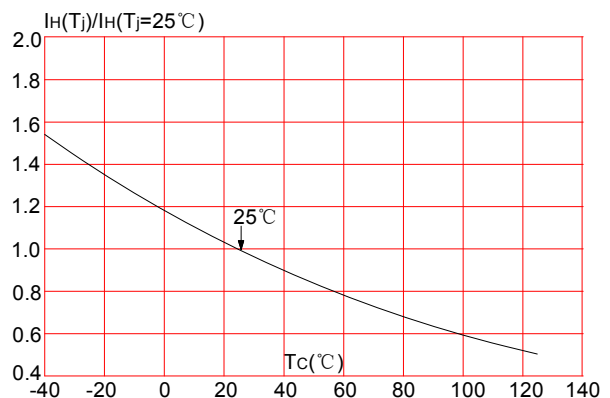
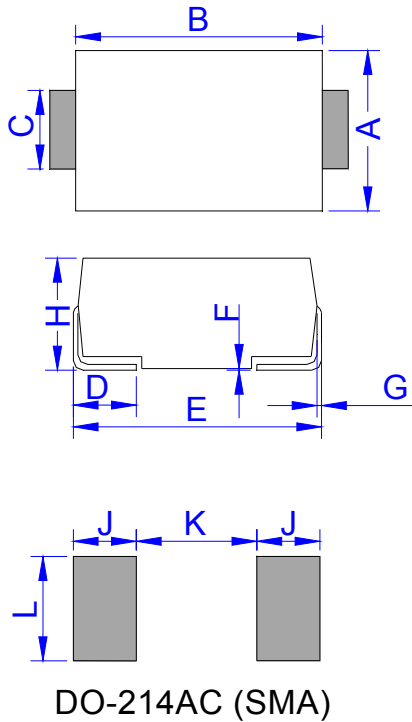


FIG.4: Normalized DC holding current vs. case temperature

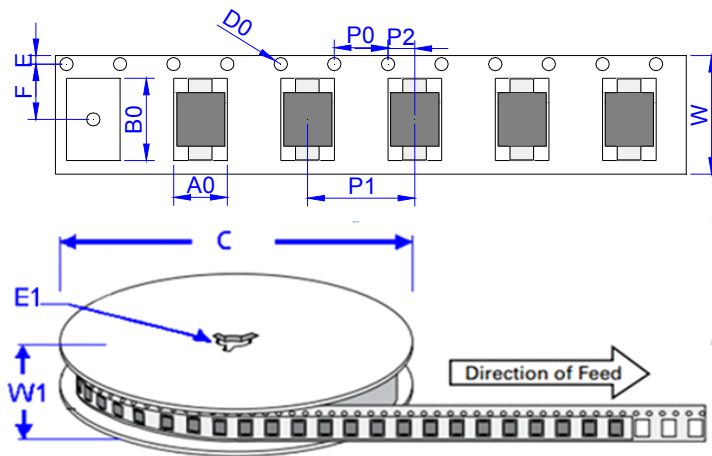


PACKAGE MECHANICAL DATA



Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	2.60	3.00	0.102	0.118
B	4.15	4.65	0.163	0.183
C	1.25	1.65	0.049	0.065
D	0.95	1.52	0.037	0.060
E	4.90	5.30	0.193	0.209
F	0.051	0.203	0.002	0.008
G	0.15	0.31	0.006	0.012
H	2.00	2.44	0.079	0.096
J	2.00		0.079	
K		2.30		0.091
L	1.80		0.071	

TAPE AND REEL SPECIFICATION-SMA



Ref.	Dimensions	
	Millimeters	Inches
A0	2.79 ± 0.3	0.110 ± 0.012
B0	5.33 ± 0.3	0.210 ± 0.012
C	330.0	13.0
D0	1.55 ± 0.1	0.061 ± 0.004
E	1.75 ± 0.2	0.069 ± 0.008
E1	13.3 ± 0.3	0.524 ± 0.012
F	5.5 ± 0.2	0.217 ± 0.008
P0	4.00 ± 0.2	0.157 ± 0.008
P1	4.00 ± 0.2	0.157 ± 0.008
P2	2.00 ± 0.2	0.079 ± 0.008
W	12.0 ± 0.2	0.472 ± 0.008
W1	15.7 ± 2.0	0.618 ± 0.079


PART No.	UNIT WEIGHT (g/PCS) typ.	REEL (PCS)	PER CARTON (PCS)	DESCRIPTION
CP0080ABN	0.066	7,500	120,000	13 inch reel pack

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